

PESDHC2FD12VU

Uni-directional 12V High Capacitance ESD Protector

Description

The PESDHC2FD12VU ESD protector is designed to replace multilayer varistors (MLVs) in portable applications such as cell phones, notebook computers, and PDA's. They feature large cross-sectional area junctions for conducting high transient currents, offer desirable electrical characteristics for board level protection, such as fast response time, lower operating voltage, lower clamping voltage and no device degradation when compared to MLVs. The PESDHC2FD12VU protects sensitive semiconductor components from damage or upset due to electrostatic discharge (ESD) and other voltage induced transient events. The PESDHC2FD12VU is available in a DFN1006-2L package with working voltages of 12 volt. It gives designer the flexibility to protect one unidirectional line in applications where arrays are not practical. Additionally, it may be "sprinkled" around the board in applications where board space is at a premium.



DFN1006-2L(Bottom View)

Feature

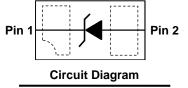
- 180W Peak pulse power per line (t_P = 8/20µs)
- DFN1006-2L package
- Replacement for MLV(0402)
- Unidirectional configurations
- Response time is typically < 1 ns</p>
- Protect one I/O or power line
- Low clamping Voltage
- RoHS compliant
- Transient protection for data lines to IEC 61000-4-2(ESD)
 ±30KV(air), ±30KV(contact); IEC 61000-4-4 (EFT) 40A (5/50ns)

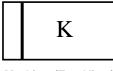
Applications

- Cell phone handsets and accessories
- Personal digital assistants (PDA's)
- Notebooks, desktops, and servers
- Portable instrumentation
- Cordless phones
- Digital cameras
- Peripherals
- MP3 players

Mechanical Characteristics

- Mounting position: Any
- Qualified max reflow temperature:260°C
- Device meets MSL 1 requirements
- DFN1006-2L without plating



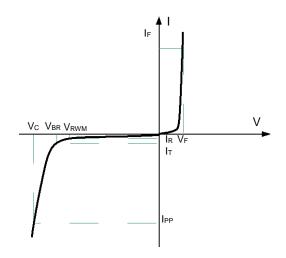


Marking (Top View)

PESDHC2FD12VU

Electronics Parameter

Symbol	Parameter		
V _{RWM}	Peak Reverse Working Voltage		
IR	Reverse Leakage Current @ VRWM		
VBR	Breakdown Voltage @ I _T		
Ι _Τ	Test Current		
IPP	Maximum Reverse Peak Pulse Current		
Vc	Clamping Voltage @ IPP		
P _{PP}	Peak Pulse Power		
CJ	Junction Capacitance		
١ _F	Forward Current		
VF	Forward Voltage @ IF		



Electrical characteristics per line@25°C(unless otherwise specified)

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Units
Peak Reverse Working Voltage	V _{RWM}				12	V
Breakdown Voltage	V _{BR}	It=1mA		14.5		V
Reverse Leakage Current	IR	V _{RWM} =12V			1	μA
Clamping Voltage	Vc	I _{PP} =8Α t _P = 8/20μs		20		V
Junction Capacitance	Cj	V _R =0V f = 1MHz		46		pF

Absolute maximum rating@25℃

Rating	Symbol	Value	Units
Peak Pulse Power (t _P = 8/20µS)	P _{pp}	180	W
Lead Soldering Temperature	ΤL	260 (10 sec)	°C
Operating Temperature	TJ	-55 to 125	°C
Storage Temperature	Тѕтс	-55 to 150	°C

PESDHC2FD12VU

Typical Characteristics

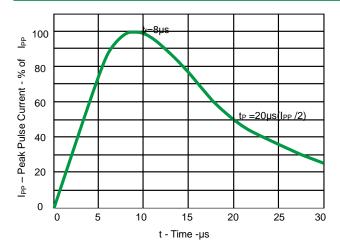
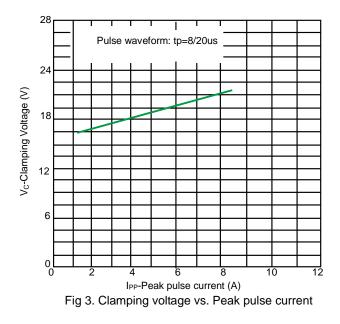


Fig 1.Pulse Waveform



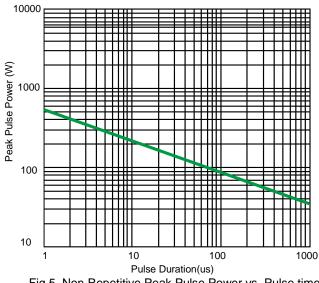


Fig 5. Non Repetitive Peak Pulse Power vs. Pulse time

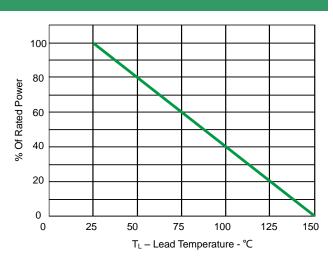
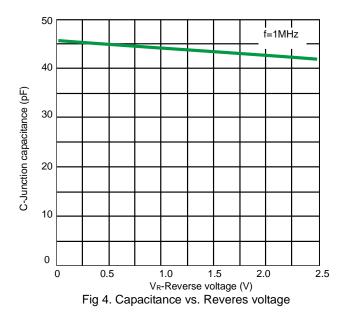
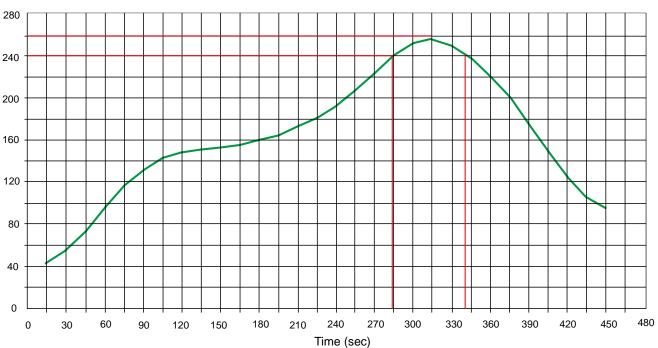


Fig 2. Power Derating Curve



PESDHC2FD12VU

Solder Reflow Recommendation



Peak Temp=257°C, Ramp Rate=0.802deg. °C/sec

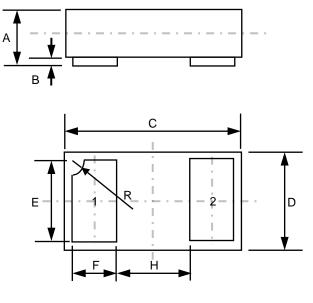
PCB Design

For TVS diodes a low-ohmic and low-inductive path to chassis earth is absolutely mandatory in order to achieve good ESD protection. Novices in the area of ESD protection should take following suggestions to heart:

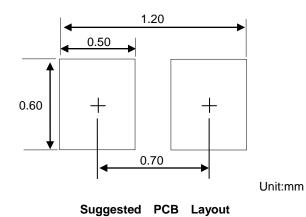
- > Do not use stubs, but place the cathode of the TVS diode directly on the signal trace.
- > Do not make false economies and save copper for the ground connection.
- > Place via holes to ground as close as possible to the anode of the TVS diode.
- > Use as many via holes as possible for the ground connection.
- > Keep the length of via holes in mind! The longer the more inductance they will have.

PESDHC2FD12VU

Product dimension (DFN1006-2L)



Dim	Inches		Millimeters		
Dim	MIN	MAX	MIN	МАХ	
А	0.013	0.020	0.34	0.50	
В	0.000	0.002	0.00	0.05	
С	0.037	0.043	0.95	1.080	
D	0.022	0.027	0.55	0.680	
E	0.016	0.024	0.40	0.60	
F	0.008	0.012	0.20	0.30	
н	0.015Typ.		0.40Тур.		
R	0.001	0.005	0.05	0.15	



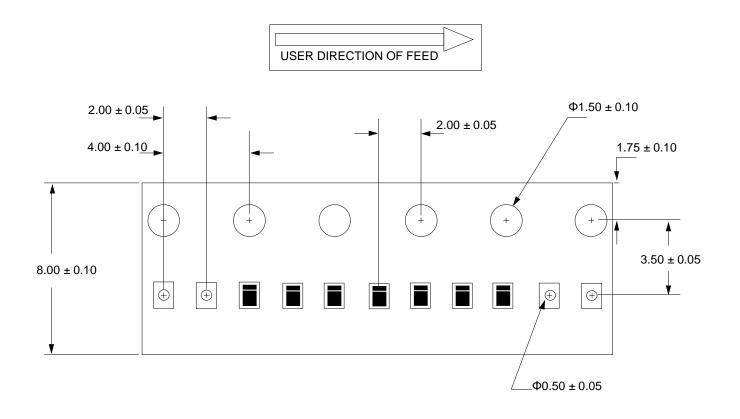
Ordering information

Device	Package	Reel	Shipping
PESDHC2FD12VU	DFN1006-2L (Pb-Free)	7"	10000 / Tape & Reel

PESDHC2FD12VU

ESD Protector

Load with information





IMPORTANT NOTICE

and **Prisemi** are registered trademarks of **Prisemi Electronics Co., Ltd** (Prisemi), Prisemi reserves the right to make changes without further notice to any products herein. Prisemi makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does Prisemi assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. "Typical" parameters which may be provided in Prisemi data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. Prisemi does not convey any license under its patent rights nor the rights of others. The products listed in this document are designed to be used with ordinary electronic equipment or devices, Should you intend to use these products with equipment or devices which require an extremely high level of reliability and the malfunction of with would directly endanger human life (such as medical instruments, aerospace machinery, nuclear-reactor controllers, fuel controllers and other safety devices), please be sure to consult with our sales representative in advance.

Website: http://www.prisemi.com For additional information, please contact your local Sales Representative. ©Copyright 2009, Prisemi Electronics Prisemi® is a registered trademark of Prisemi Electronics. All rights are reserved.